

# 國立中山大學 102 學年度碩士暨碩士專班招生考試試題

科目名稱：電子學【電機系碩士班甲組、乙組、戊組、電波領域聯合】

題號：431005

※本科目依簡章規定「可以」使用計算機（廠牌、功能不拘）

共 2 頁第 1 頁

1. (20%) (a) What is the amplifier configuration in Figure 1. (b) Explain why the  $R_S$  can improve the thermal stability of the amplifier. (c) Please derive  $R_i$ ,  $R_{in}$ ,  $A_{VO}$ ,  $A_V$ ,  $G_{VO}$ ,  $G_V$ ,  $R_o$  and  $R_{out}$  of the amplifier in Figure 1. (2%, 2%, 2%\*8)

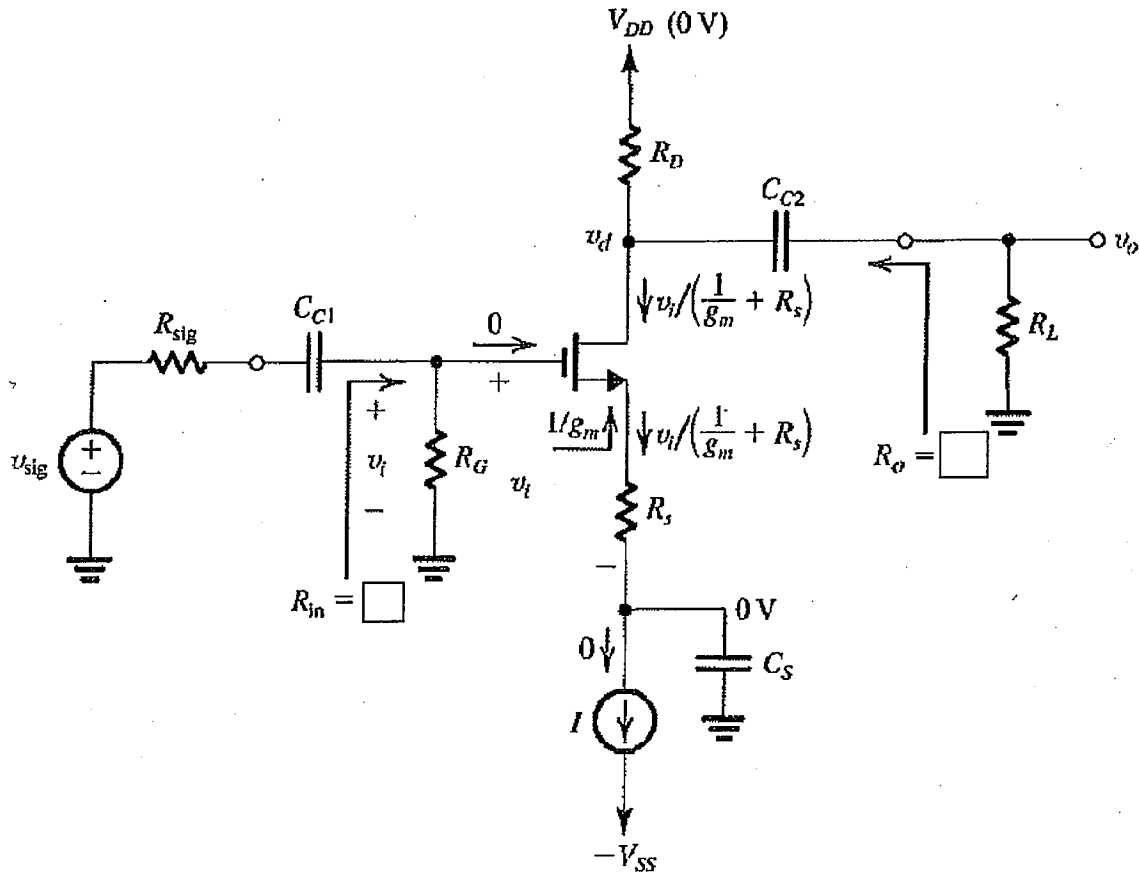


Figure 1

2. (20%) Figure 2 shows an op amp connected in the inverting configuration. The op amp has an open-loop gain  $\mu = 10^4$ , a differential input resistance  $R_{id} = 100\text{k}\Omega$ , and an output resistance  $r_o = 1\text{k}\Omega$ . Use the feedback method to find (a) the voltage gain  $V_o/V_s$ , (b) the input resistance  $R_{in}$ , and (c) the output resistance  $R_{out}$ . (7%, 7%, 6%)

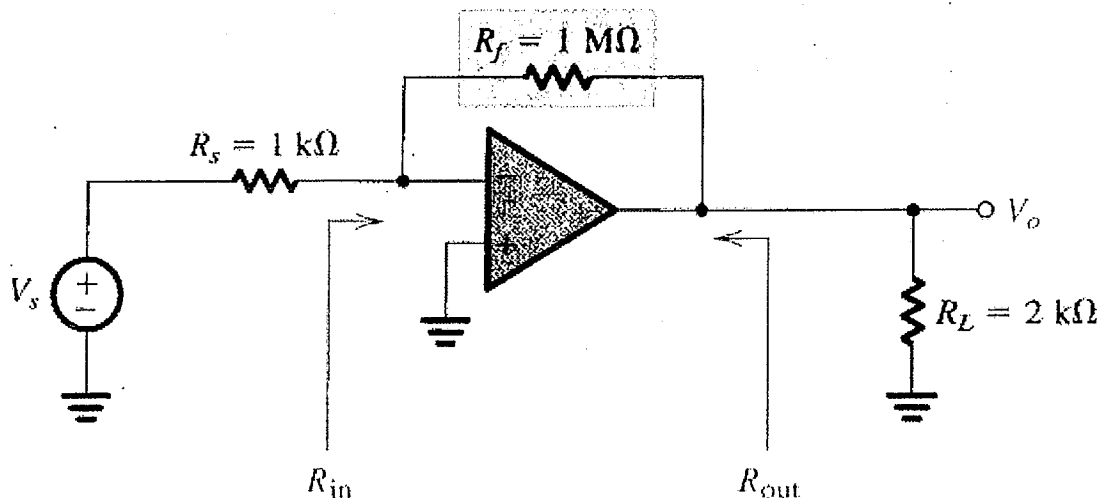


Figure 2.

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3. (20%) (a) Draw an ENH mode NMOS (enhancement nMOSFET) and a DEP mode NMOS (depletion nMOSFET) respectively. Please explain what are the differences of (b) their fabrication processes and the differences between (c) their input characteristics  $I_{DS}-V_{GS}$  and (d) their output characteristics  $I_{DS}-V_{DS}$ , respectively. (5%, 5%, 5%, 5%)
4. (20%) (a) Using a simple ( $r_\pi$  and  $g_m$ ) model for each of the two transistors  $Q_{18}$  and  $Q_{19}$  in Figure 4.a, find the small-signal resistance between  $A$  and  $A'$ . Where  $I_{C18} = 165 \mu A$  and  $I_{C19} = 16 \mu A$ . (b) Figure 4.b shows the circuit for determine the 741 op-amp output resistance when  $v_O$  is positive and  $Q_{14}$  is conducting most of the current. Using the resistance of the  $Q_{18}$  and  $Q_{19}$  network calculated in 4.(a) and neglecting the large output resistance of  $Q_{13A}$ , find  $R_o$  when  $Q_{14}$  is sourcing an output current of 5mA. (10%, 10%)

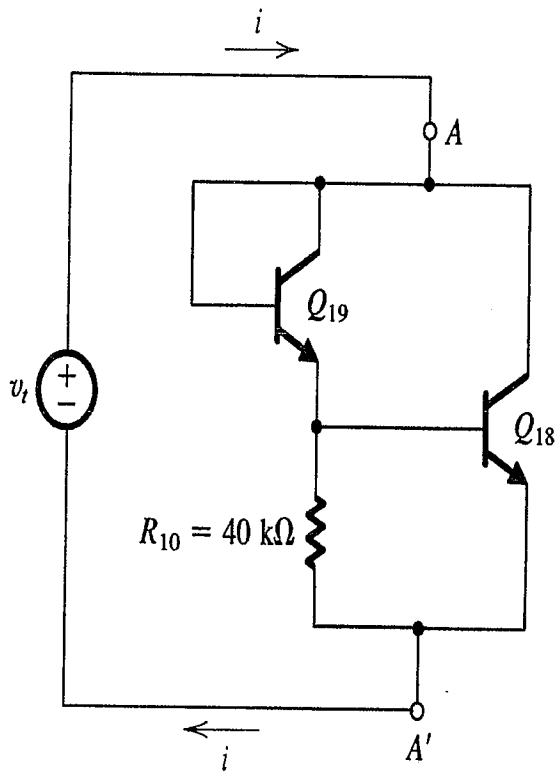


Figure 4.a

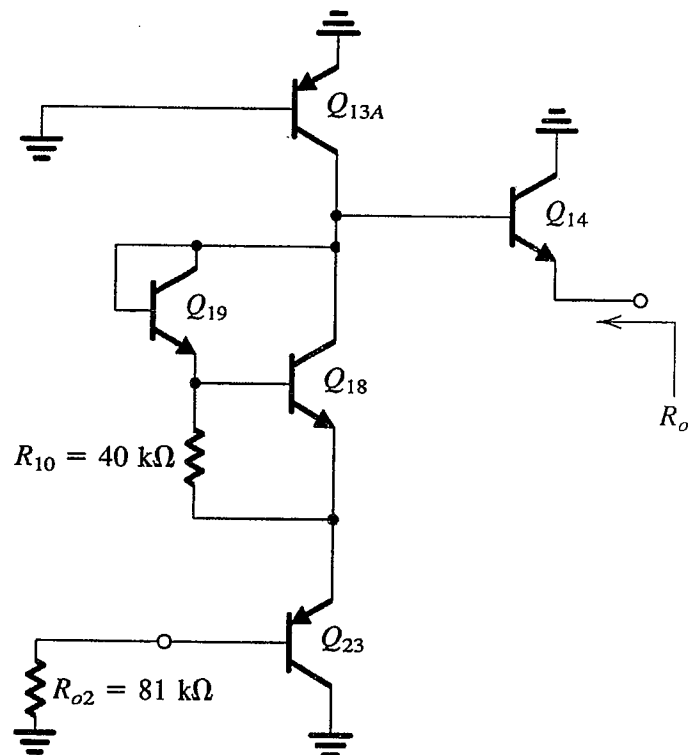


Figure 4.b

5. (20%) (a) Plot a Bridge full-wave rectifier and (b) explain the operation principle of it. Also, (c) please describe how to drive the PIV (peak inverse voltage) of the diodes used. (7%, 7%, 6%)